VS-20ETS08FP-M3, VS-20ETS12FP-M3

Vishay Semiconductors

ROHS

HALOGEN

FREE

High Voltage, Input Rectifier Diode, 20 A





TO-220 FullPAK 2L

| PRIMARY CHARACTERISTICS | | | | |
|----------------------------------|-------------------|--|--|--|
| I _{F(AV)} | 20 A | | | |
| V _R | 800 V, 1200 V | | | |
| V _F at I _F | 1.1 V | | | |
| I _{FSM} | 300 A | | | |
| T _J max. | 150 °C | | | |
| Package | TO-220 FullPAK 2L | | | |
| Circuit configuration | Single | | | |

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL pending
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

| OUTPUT CURRENT IN TYPICAL APPLICATIONS | | | | | | |
|---|---------------------------|----|---|--|--|--|
| APPLICATIONS | SINGLE-PHASE BRIDGE UNITS | | | | | |
| Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W | 18 | 22 | A | | | |

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|-----------------------------------|------------------------------|-------------|-------|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | |
| I _{F(AV)} | Sinusoidal waveform | 20 | А | | | |
| V _{RRM} | Range | 800, 1200 | V | | | |
| I _{FSM} | | 300 | А | | | |
| V _F | 10 A, T _J = 25 °C | 1.0 | V | | | |
| TJ | | -40 to +150 | °C | | | |

| VOLTAGE RATINGS | | | | | | | |
|-----------------|---|---|-------------------------------------|--|--|--|--|
| PART NUMBER | V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} AT 150 °C mA | | | | |
| VS-20ETS08FP-M3 | 800 | 900 | 4 | | | | |
| VS-20ETS12FP-M3 | 1200 | 1300 | ' | | | | |



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| ABSOLUTE MAXIMUM RATINGS | 3 | | | |
|--------------------------------------|--------------------|--|--------|------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum average forward current | I _{F(AV)} | T _C = 51 °C, 180° conduction half sine wave | 20 | |
| Maximum peak one cycle | | 10 ms sine pulse, rated V _{RRM} applied | 250 | Α |
| non-repetitive surge current | I _{FSM} | 10 ms sine pulse, no voltage reapplied | 300 | |
| Maximum I ² t for fusing | l ² t | 10 ms sine pulse, rated V _{RRM} applied | 316 | A ² s |
| Maximum I-t for fusing I-t | 1-1 | 10 ms sine pulse, no voltage reapplied | 442 | A-S |
| Maximum I ² √t for fusing | I ² √t | t = 0.1 ms to 10 ms, no voltage reapplied | 4420 | A²√s |

| ELECTRICAL SPECIFICATIONS | | | | | |
|---------------------------------|--------------------|------------------------------|---|--------|-------|
| PARAMETER | SYMBOL | TEST (| CONDITIONS | VALUES | UNITS |
| Maximum forward voltage drop | V_{FM} | 20 A, T _J = 25 °C | | 1.1 | V |
| Forward slope resistance | r _t | T _J = 150 °C | | 10.4 | mΩ |
| Threshold voltage | V _{F(TO)} | | | 0.85 | V |
| Maximum reverse leakage current | I _{RM} | T _J = 25 °C | - V _R = Rated V _{RRM} | 0.1 | mA |
| | | T _J = 150 °C | | 1.0 | IIIA |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | |
|---|------------|-----------------------------------|---------------------------------------|-------------|------------------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction and storage tempera | ture range | T _J , T _{Stg} | | -40 to +150 | °C |
| Maximum thermal resistance, junction to case | | R _{thJC} | DC operation | 2.8 | |
| Maximum thermal resistance, junction to ambient | | R _{thJA} | | 62 | °C/W |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth, and greased | 0.5 | |
| Approximate weight | | | | 2 | g |
| Approximate weight | | | | 0.07 | OZ. |
| Mauratin r. Accessor | | | | 6.0 (5.0) | kgf · cm |
| Mounting torque max | maximum | | | 12 (10) | (lbf \cdot in) |
| | | | Coop at do TO 200 FullPAIX 0 | 20ETS08FP | |
| Marking device | | | Case style TO-220 FullPAK 2L | 20ETS | S12FP |

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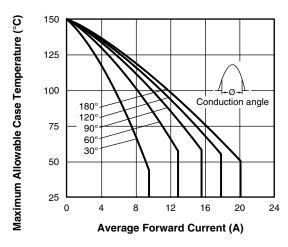


Fig. 1 - Current Rating Characteristics

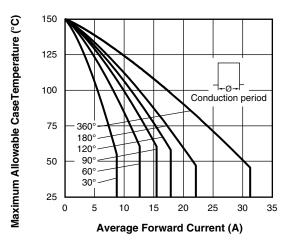


Fig. 2 - Current Rating Characteristics

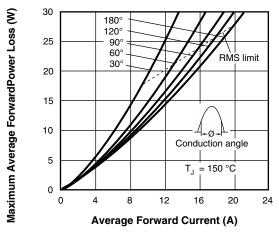


Fig. 3 - Forward Power Loss Characteristics

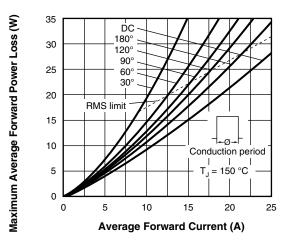


Fig. 4 - Forward Power Loss Characteristics

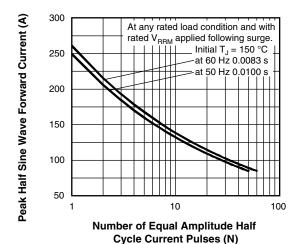


Fig. 5 - Maximum Non-Repetitive Surge Current

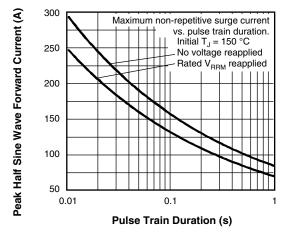


Fig. 6 - Maximum Non-Repetitive Surge Current

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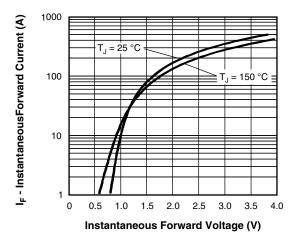


Fig. 7 - Forward Voltage Drop Characteristics

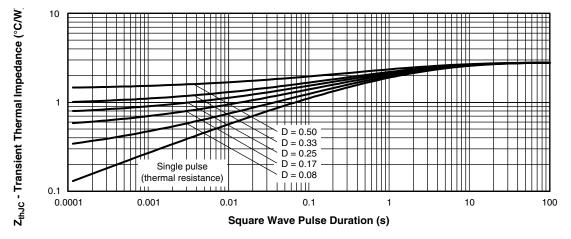


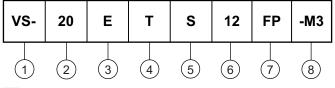
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- Current rating (20 = 20 A)

- Circuit configuration:

E = single diode

- Package:

4 T = TO-220

- Type of silicon:

S = standard recovery rectifier

08 = 800 V 12 = 1200 V

Voltage ratings

7 - FullPAK

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | |
| VS-20ETS08FP-M3 | 50 | 1000 | Antistatic plastic tubes | | | |
| VS-20ETS12FP-M3 | 50 | 1000 | Antistatic plastic tubes | | | |

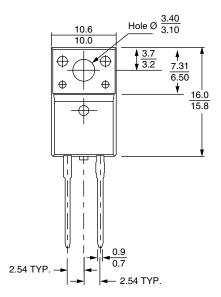
| LINKS TO RELATED DOCUMENTS | | | | |
|--|--------------------------|--|--|--|
| Dimensions <u>www.vishay.com/doc?96157</u> | | | | |
| Part marking information | www.vishay.com/doc?95392 | | | |

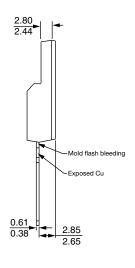


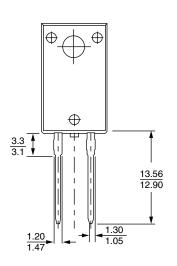
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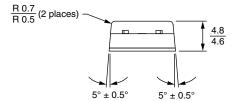
2L TO-220 FullPAK

DIMENSIONS in millimeters









Bottom view



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